DESCRIPTION

The TS19460 is an average current mode control LED driver IC operating in a constant off-time mode. It greatly improves accuracy, line and load regulation of the LED current without any need for loop compensation or high-side current sensing. The output LED current accuracy is at  $\pm 5\%$ , and it is equipped with current limit comparator for hiccup mode output short circuit protection.

The TS19460 can be powered from an 8V~450V supply. A PWM dimming input is provided that accepts an external control TTL compatible signal. The output current can be programmed by an internal 250mV reference, or controlled externally through a 0~1.5V dimming input. The TS19460 is ideally suited for buck LED drivers and is requires only free external components (apart from the power stage) to produce a controlled LED current making it an ideal solution for low cost LED drivers.

Notes: Moisture sensitivity level: level 3. Per J-STD-020

TYPICAL APPLICATION CIRCUIT

### FEATURES

AC/DC WLED Driver with Average-Mode Constant Current Control

- Fast average current controller
- Programmable constant off-time switching
- Linear and PWM dimming capability
- Requires few external components for operation
- Output short circuit protection with skip mode
- Pin –compatible with TS19450CS

#### APPLICATION

- DC/DC or AC/DC LED driver applications
- RGB backlighting LED driver
- Back lighting of flat panel displays
- General purpose constant current source
- Signage and decorative LED lighting
- LED street lighting

8. RT 7. LD

6. V<sub>DD</sub>

D1 י

Rcs

L1

TSM1N45CT

5. PWMD

Cout

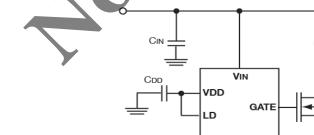
Pin Definition: 1. V<sub>IN</sub> 8

2. CS

CS

GND

PWMD RT 3. GND 4. Gate



SOP-8

TS19460 Taiwan Semiconductor





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ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise specified) (Note 1)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Input Voltage Range	V <sub>IN</sub> to GND	-0.5 ~ +470	V	
Internal Regulated Voltage	V <sub>DD</sub> to GND	12	V	
CS, LD, PWMD, Gate, RT to GND		-0.3 ~ (V <sub>DD</sub> +0.3)	V	
Continuous Power Dissipation (Note 2)	P <sub>D</sub>	650	mW	
Storage Temperature Range	T <sub>A</sub>	-65 to +150	°C	
Junction Temperature Range	TJ	-40 to +150	°C	
			·	

THERMAL PERFORMANCE (Note 3)			
PARAMETER	SYMBOL	LIMIT	UNIT
Thermal Resistance – Junction to Ambient	R <sub>θJA</sub>	128	°C/W

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C, V <sub>IN</sub> = 12V, V <sub>LD</sub> =PWM=V <sub>DD</sub> , unless otherwise noted) (Note 4)						
PARAMETER	SYMBOL	CONDITION	MIN	ТҮР	MAX	UNIT
Input	Input					
DC Input Voltage Range	VINDC	DC input voltage	8.0		450	V
Shut-down Mode Supply Current	I <sub>INSD</sub>	Pin PWMD to GND		0.5	1.0	mA
Internal Regulator						
Internally Regulated Voltage	V <sub>DD</sub>	$V_{IN}=8V$ , $I_{DD(EXT)}=0$ , 500pF at Gate, $R_{T}=226k\Omega$	7.25	7.5	7.75	V
Line Regulation of V <sub>DD</sub>		V <sub>IN</sub> =8~450V, I <sub>DD(EXT)</sub> =0 500pF at Gate, R <sub>T</sub> =226kΩ	0		1.0	V
Load Regulation of V <sub>DD</sub>	$\Delta V_{DDLoad}$	$I_{DD(EXT)}= 0 \sim 1mA$ 500pF at Gate, R <sub>T</sub> =226kΩ	0		100	mV
Undervoltage Lockout Threshold	UVLO	V <sub>IN</sub> rising	6.45	6.7	6.95	V
Undervoltage Lockout Hysteresis	ΔUVLO	V <sub>IN</sub> falling		500		mV
Maximum Input Current	I <sub>IN (MAX)</sub>	V <sub>IN</sub> =8V	3.5			mA
Dimming						
PWMD Input Low Voltage	V <sub>ENL</sub>	V <sub>IN</sub> =8V~450V			0.8	V
PWMD Input High Voltage	V <sub>ENH</sub>	V <sub>IN</sub> =8V~450V	2.0			V
PWMD Pull-down resistance at PWMD	R <sub>EN</sub>	V <sub>PWMD</sub> =5V	50	100	150	kΩ



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PARAMETER	SYMBOL	CONDITION	MIN	ТҮР	MAX	UNIT
Average Current Sense Logic						
Current Sense Reference Voltage	V <sub>cs</sub>		238	250	262	mV
LD to Current Sense Ratio	Av <sub>(LD)</sub>			0.18		mV
LD input Voltage Shutdown	V <sub>LD(OFF)</sub>	V <sub>LD</sub> falling		150		mV
LD input Voltage Enable	$\Delta V_{\text{LD(OFF)}}$	V <sub>LD</sub> rising		200		mV
Current Sense Blanking Interval	T <sub>BLANK</sub>		150		280	ns
Minimum On-Time	T <sub>ON(min)</sub>	$V_{CS} = V_{CS} + 30 mV$				μS
0" T	-	R <sub>T</sub> =1MΩ	32		48	
Off Time	T <sub>OFF</sub>	R <sub>T</sub> =226kΩ	8		12	μS
Max. Steady-State Duty Cycle	D <sub>MAX</sub>		75			%
Short Circuit Protection						
Hiccup Threshold Voltage	V <sub>cs</sub>		410		470	mV
Current Limit Delay CS to Gate	T <sub>DELAY</sub>	$V_{CS} = V_{CS} + 30 mV$			150	ns
Short Circuit Hiccup Time	T <sub>HICCUP</sub>		330		460	μS
Minimum On-Time (Short Circuit)	T <sub>ON(min)</sub>	V <sub>CS</sub> = V <sub>DD</sub>			430	μS
Gate Driver						
Gate Sourcing Current	ISOURCE	$V_{GATE}=0V, V_{DD}=7.5V$	165			mA
Gate Sinking Current	I <sub>SINK</sub>	V <sub>GATE</sub> =V <sub>DD</sub> , V <sub>DD</sub> =7.5V	165			mA
Gate Output Rise Time	T <sub>RISE</sub>	C <sub>GATE</sub> =500pF, V <sub>DD</sub> =7.5V		30	50	ns
Gate Output Fall Time	TFALL	C <sub>GATE</sub> =500pF, V <sub>DD</sub> =7.5V		30	50	ns

Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These 1. are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

2. Limited by package power dissipation, whichever is lower.

3. Thermal Resistance is specified with the component mounted on a low effective thermal conductivity test board in free air at  $T_A=25^{\circ}C$ .

4. Denotes the specifications which apply over the full operating ambient temperature range of -40°C<T<sub>A</sub><+125°C.



### **ORDERING INFORMATION**

PART NO.	PACKAGE	PACKING
TS19460CS RLG	SOP-8	2,500pcs / 13" Reel

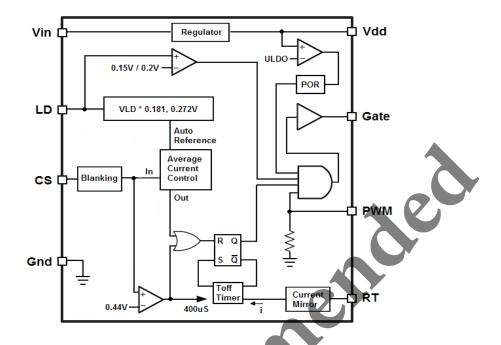
Note:

the states 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC.

2. Halogen-free according to IEC 61249-2-21 definition.



## FUNCTION BLOCK DIAGRAM



## **PIN DESCRIPTION**

PIN NO.	NAME	FUNCTION
1	VIN	This pin is the input of 8V~450V linear regulator
2	CS	This pin is the current sense pin used to sense the MOSFET current by means of an external sense resistor.
3	GND	Ground return for all internal circuitry. This pin must be electrically connected to the ground of the power train.
4	GATE	This pin is the output GATE driver for an external N-CH Power MOSFET
5	PWMD	This is the PWM dimming input of the IC. When this pin is pulled to GND, the Gate Driver is turned off. When the pin is pulled high, the GATE driver operates normally.
6	VDD	This is the power supply pin for all internal circuits. It must be bypassed with a low ESR capacitor to GND (≥0.1µF)
7	LD	This pin is the linear dimming input and sets the current sense threshold as long as the voltage at the pin is less than 1.5V, The Gate output is disable when LD voltage <150mV(typ.) and recovery when LD voltage >200mV (typ.)
8	RT	A resistor is connected between RT and GND to program the Gate off-time.



## **APPLICATION INFORMATION**

The TS19460 is optimized to drive buck LED drivers using average current mode control. This method of control enables fairly accurate LED current control without the need for high side current sensing or the design of any closed loop controllers. The IC uses very few external components and enables both linear and PWM dimming of the LED current.

A resistor connected to the RT pin programs the off-time. Constant off-time control average current mode is used for stability and to improve the LED current regulation over a wide range of input voltages.

The current through the switching MOSFET source is averaged and used to give constant-current feedback. This current is detected from a sense resistor at the CS pin, the feedback operates in a fast open-loop mode, there is no compensation required, the output current is programmed as

### $I_{LED} = 0.25V / R_{CS}$

When the Voltage at the LD input >1.5V, otherwise

### $I_{LED} = (V_{LD} * 0.181) / R_{CS}$

When application to design the inductor witching ripple current in it is 40% of average peak to peak, full load current, the inductance can be calculated as follow:

### $L_{OUT} = (V_{OUT(max)} * T_{OFF}) / (0.4 * I_{OUT})$

The duty cycle range of current control feedback is limited to duty <75%, A reduction in the LED current string voltage is greater than 75% of input voltage.

Reducing the output LED voltage is below  $V_{OUT(MIN)} = V_{IN} * D_{(MIN)}$ , where  $D_{(MIN)} = 1 \text{ uS} / (T_{OFF} + 1 \text{ uS})$ , may also result in the loss of regulation of LED current. This condition will cause an increase in the LED current and can be possible to trip the short circuit protection comparator.

The short circuit protection comparator trips when the voltage at CS exceeds 0.44V, the Gate off time ( $T_{HICCUP}$  = 400µs) is generated to prevent stair-casing of inductor current and potentially its saturation due to insufficient output voltage.

The leading edge blanking delay is provided at CS to prevent false triggering of current feedback and short circuit protection.



The TS19460 can be powered directly from its  $V_{IN}$  pin and can work from  $8.0V_{DC}$ ~450 $V_{DC}$  at its  $V_{IN}$  pin. When a voltage is applied at the  $V_{IN}$  pin, the TS19460 maintains a constant 7.5V at the  $V_{DD}$  pin. This voltage is used to power the IC and any external resistor dividers needed to control the IC. The  $V_{DD}$  pin must be bypassed by a low ESR capacitor to provide a low impedance path for the high frequency current of the output GATE driver. The TS19460 can be also operated by supplying a voltage at the  $V_{DD}$  pin greater than the internally regulated voltage. Please note that this external voltage at the  $V_{DD}$  pin should not exceed 12V.

Although the V<sub>IN</sub> pin of the TS19460 is rated up to 450V, the actual maximum voltage that can be applied is limited by the power dissipation in the IC. For example, if an SOP-8 (junction to ambient thermal resistance  $R\theta_{JA} = 128^{\circ}C/W$ ) TS19460 draws about  $I_{IN} = 2.0mA$  from the V<sub>IN</sub> pin, and has a maximum allowable temperature rise of the junction temperature limited to about the maximum voltage at the V<sub>IN</sub> pin would be:

 $V_{IN(MAX)} = (T_{J(MAX)} - T_A) / (R\theta_{JA} * I_{IN}) = 390V$ 

## **APPLICATION INFORMATION (CONTINUE)**

In these cases, to operate the TS19460 from higher input voltages, a Zener diode can be added in series with the VIN pin to divert some of the power loss from the TS19460 to the Zener diode. In the above example, using a 100V Zener diode will allow the circuit to easily work up to 490V.

The input current drawn from the  $V_{IN}$  pin is a sum of the 1.0mA current drawn by the internal circuit and the current drawn by the GATE driver (which in turn depends on the switching frequency and the GATE charge of the external.

#### $I_{IN} \approx 1mA + Q_G x f_S$

In the above equation,  $f_s$  is the switching frequency and  $Q_G$  is the GATE charge of the external MOSFET (which can be obtained from the datasheet of the MOSFET).

#### **Oscillator**

The oscillator in the TS19460 is controlled by a single resistor connected at the RT pin. The equation governing the off-time of the GATE output is given by:

 $T_{OFF(\mu S)} = (RT_{(k\Omega)} / 25) + 0.3$ 

\*within the range of  $30k\Omega \le R_T \le 1M\Omega$ 

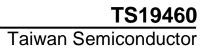
#### Linear Dimming

The Linear Dimming pin is used to control the LED current, when voltage at LD is fall below 1.5V, the internal reference voltage (250mV) to the constant current feedback become over ridden by  $V_{LD}$  \* 0.181, and the current in the inductor remain continuous, the LED current is given by  $I_{LED} = (V_{LD} * 0.181) / R_{CS}$ , The Gate output is disable when LD voltage <150mV(typ.) and recovery when LD voltage >200mV (typ.)

The Linear Dimming input could also be used for mixed-mode dimming to expand the dimming ratio, in this kind of application condition, the pulse-width modulated signal of a measured amplitude below 1.5V should be applied at LD.

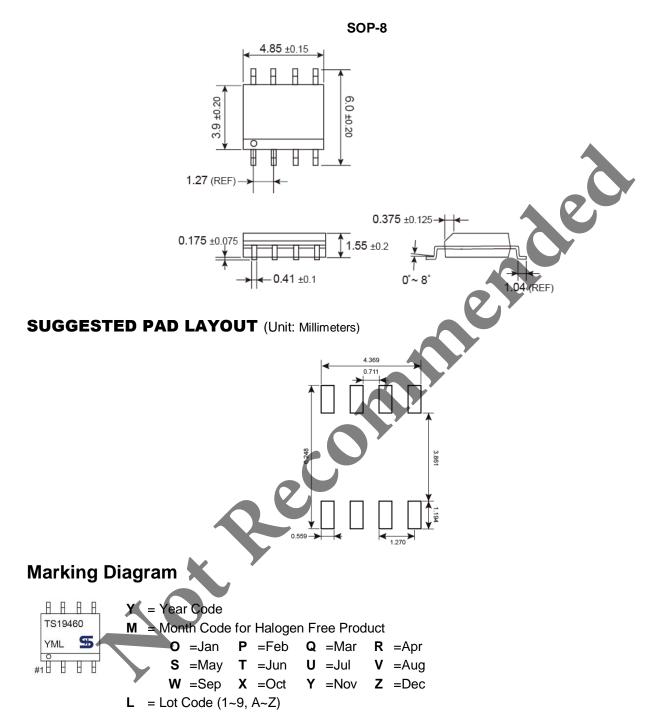
#### PWM Dimming

PWM Dimming can be achieved by driving the PWMD pin with a square wave signal. The rising and falling edges are limited by current slew rate in inductor, the first switching cycle is terminated upon reaching the level (250mV) at CS, the circuit is further reaching its steady state within 3~5 switching cycle regardless of the switching frequency.

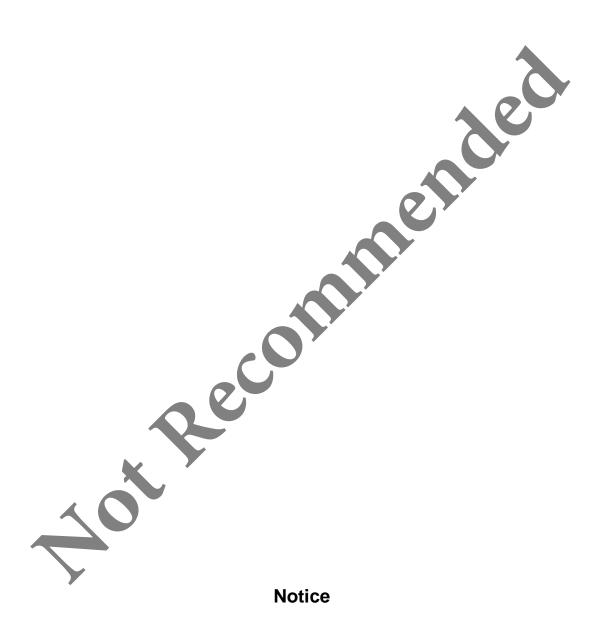




## PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)







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